NSN 5961-00-110-0937

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-110-0937 **Inclosure Material:** Metal **Overall Length:** Between 0.666 inches and 0.686 inches **Overall Height:** 0.260 inches **Overall Width:** 0.390 inches **Function For Which Designed:** Switching **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -300.0 collector to base voltage/static/emitter open and -5.0 emitter to base voltage, static, collector open and -300.0 collector-to-emitter, resistance between base and emitter **Current Rating Per Characteristic:** Between -1.00 amperes source cutoff current and -3.00 amperes source cutoff current **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-00-110-0937 Transistor - Page 2 of 2



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